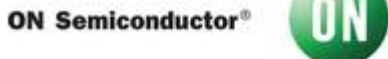
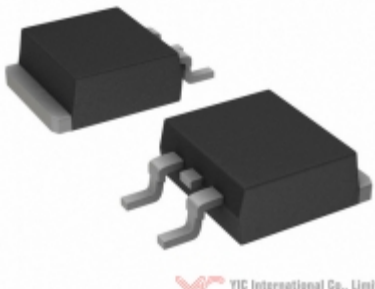


| | |
|---|--|
|  | <h2 style="color: red;">FQB10N20TM</h2> |
|  | <p>Hersteller-Teilenummer: FQB10N20TM</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 200V 10A D2PAK</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 49875 pcs Stock Available.</p> <p>Lieferroute von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|---|
| Teilenummer | FQB10N20TM |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 200V 10A D2PAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 49875 pcs Stock |
| detaillierte Beschreibung | N-Channel 200V 10A (Tc) Surface Mount D ² PAK (TO- |
| Serie | QFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB |
| Supplier Device-Gehäuse | D ² PAK (TO-263AB) |
| Verlustleistung (max) | - |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (V _{dss}) | 200V |
| Strom - Ununterbrochener Abfluss (I _d) bei 25 ° C | 10A (Tc) |
| R _{ds On} (Max) @ I _d , V _{gs} | 360 mOhm @ 5A, 10V |
| V _{GS} (th) (Max) @ I _d | 5V @ 250µA |
| Gate Charge (Q _g) (Max) @ V _{gs} | 18nC @ 10V |
| Eingabekapazität (C _{iss}) (Max) @ V _{ds} | 670pF @ 25V |
| Antriebsspannung (Max R _{ds On} , Min R _{ds On}) | 10V |
| V _{gs} (Max) | ±30V |
| Verpackung | Tape & Reel (TR) |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |

FQB10N20TM ist neu im Original, Suche FQB10N20TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB10N20TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB10N20TM: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|---|--|---|
|  <p>FQB10N20CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 9.5A D2PAK</p> |  <p>FQB10N50CF FAIRCHI FQB10N50CF FAIRCHI</p> |  <p>FQB10N20LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 10A D2PAK</p> |  <p>FQB10N50CFTM_WS Fairchild/ON Semiconductor FQB10N50CFTM_WS Fairchild/ON Semiconductor</p> |
|  <p>FQB10N20LTM Fairchild/ON Semiconductor MOSFET N-CH 200V 10A D2PAK</p> |  <p>FQB10N20L FAIRCHILD FQB10N20L FAIRCHILD</p> |  <p>FQB10N50CFTM FSC FQB10N50CFTM FSC</p> |  <p>FQB10N50CFTM-WS AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 10A DPAK</p> |

heiße Teile

Mehr

| | | | | |
|--------------------|--------------------|----------------------|----------------|--------------------|
| ⊛ FQB10N20C | ↔ FQB10N20CTM | ⇒ FQB10N20CTM | D FQB10N20L | ⇒ FQB10N20LTM |
| ⊣ FQB10N20LTM | ⊛ FQB10N20TM | D FQB10N50CF | ⇒ FQB10N50CFTM | ⇒ FQB10N50CFTM_WS |
| ⊛ FQB10N60C | ⊣ FQB10N60CTM | ⊛ FQB10N60CTM | ↔ FQB11N40 | ⇒ FQB11N40C |
| D FQB11N40CTM | ⊛ FQB11N40CTM | ⊣ FQB11N60FTM | ⊛ FQB11N60TM | ⇒ FQB11P06 |
| ⇒ FQB11P06TM | ↔ FQB11P06TM | ⊛ FQB11P06TM**CN-SCI | ⊣ FQB12N50TM | ⇒ FQB12N50TM_AM002 |
| ↔ FQB12N50TM_AM002 | ⇒ FQB12N60 | D FQB12N60C | ⊛ FQB12N60CTM | ⊣ FQB12N60CTM |
| ⊛ FQB12N60TM | D FQB12N60TM_AM002 | ⇒ FQB12N60TM_AM002 | ↔ FQB12P10 | ⇒ FQB12P10TM |
| ⊣ FQB12P10TM | ⊛ FQB12P20 | ↔ FQB12P20TM | ⇒ FQB12P20TM | ⇒ FQB13N06L |
| ⊛ FQB13N10 | ⊣ FQB13N10L | ⊛ FQB13N50 | D FQB13N50CTM | ⇒ FQB13N50CTM |
| ↔ FQB140N03L | ⊛ FQB14N30TM | ⊣ FQB14N30TM | ⊛ FQB16N25TM | ⇒ FQB16N25TM |

Contact us: Info@Y-IC.com

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